

1. General description

AC Thyristor Triac power switch in a SOT404 (D2PAK) surface mountable plastic package with self-protective clamping capabilities against low and high energy transients.

2. Features and benefits

- Clamping structure ensuring safe high over-voltage withstand capability
- Pin compatible with standard triacs
- Full cycle AC conduction
- Over-voltage withstand capability to IEC 61000-4-5
- Planar passivated for voltage ruggedness and reliability
- Protective self turn-on capability for high energy transients
- Safe clamping capability for low energy over-voltage transients
- Less sensitive gate for high noise immunity
- Triggering in three quadrants only
- Very high immunity to false turn-on by dV/dt and IEC 61000-4-4 fast transient
- Enhanced dynamic performance
- Surface mountable package
- Package is RoHS compliant
- Package meets UL94V0 flammability requirement

3. Applications

- Fan motor circuits
- Highly inductive, resistive and safety loads
- · Loads such as contactors, circuit breakers, valves, dispensers and door locks
- Pump motor circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DRM}	repetitive peak off- state voltage		-	-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 109 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-	-	6	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 16.7 ms	-	-	66	A
		full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>	-	-	60	A
Tj	junction temperature		-	-	125	°C

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{PP}	peak pulse voltage	T _j = 25 °C; non-repetitive, off-state; Fig. <u>6</u>	-	-	2	kV
Static chara	acteristics	·	· · ·			
I _{GT}	gate trigger current	V_D = 12 V; I _T = 100 mA; LD+ G+; T _j = 25 °C; <u>Fig. 8</u>	5	-	35	mA
		V _D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 8</u>	5	-	35	mA
		V _D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 8</u>	5	-	35	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 10</u>	-	-	40	mA
V _T	on-state voltage	I _T = 8 A; T _j = 25 °C; <u>Fig. 11</u>	-	-	1.65	V
V _{CL}	clamping voltage	I _{CL} = 0.1 mA; t _p = 1 ms; T _j = 25 °C	800	-	-	V
Dynamic ch	naracteristics	·	· · ·			
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	1500	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 125 \text{ °C}; \text{ I}_{T(RMS)} = 6 \text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu\text{s}; \text{ (snubberless condition); gate open circuit}$	12	-	-	A/ms
		V_D = 400 V; T _j = 125 °C; I _{T(RMS)} = 6 A; dV _{com} /dt = 10 V/µs; gate open circuit	15	-	-	A/ms
		V_D = 400 V; T _j = 125 °C; I _{T(RMS)} = 6 A; dV _{com} /dt = 1 V/µs; gate open circuit	20	-	-	A/ms

5. Pinning information

Table 2. F	Table 2. Pinning information							
Pin	Symbol	Description	Simplified outline	Graphic symbol				
1	СМ	common	mb	LD				
2	LD	load						
3	G	gate	ii	G—				
mb	LD	mounting base; load	D2PAK (SOT404)	CM 003aaf296				

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
ACTT6B-800CN	D2PAK	plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped)	SOT404			

7. Marking

Table 4. Marking codes	
Type number	Marking code
ACTT6B-800CN	ACTT6B-800CN

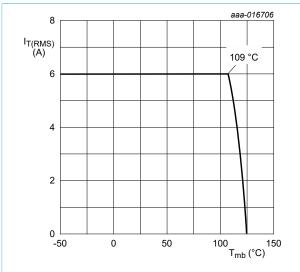
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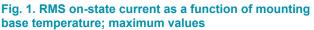
8. Limiting values

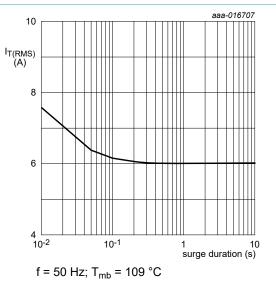
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; $T_{mb} \le 109 \text{ °C}$; <u>Fig. 1</u> ; Fig. 2; Fig. 3	-	6	A
I _{TSM}	non-repetitive peak on-	full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	66	А
	state current	full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig. 4; Fig. 5	-	60	A
l ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	-	18	A²s
dl _T /dt	rate of rise of on-state current	I _G = 70 mA	-	100	A/µs
I _{GM}	peak gate current	t = 20 µs	-	2	А
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
Tj	junction temperature		-	125	°C
V _{PP}	peak pulse voltage	T _i = 25 °C; non-repetitive, off-state; <u>Fig. 6</u>	-	2	kV

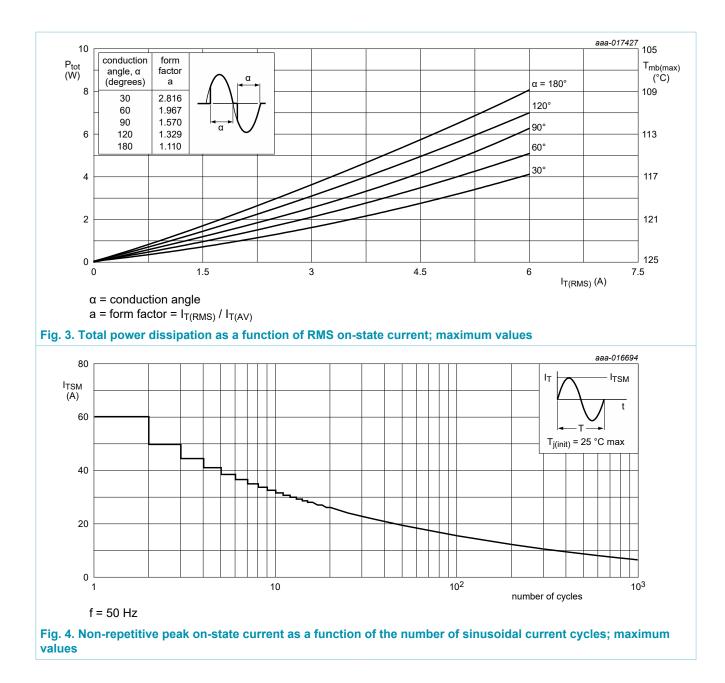








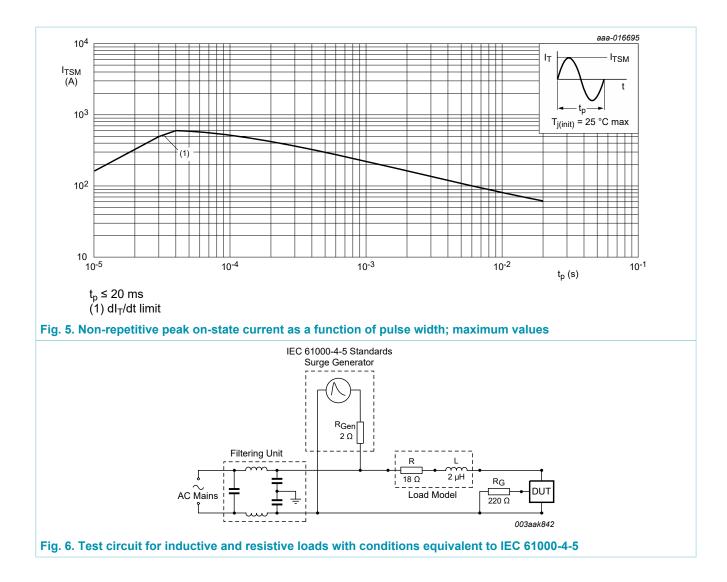
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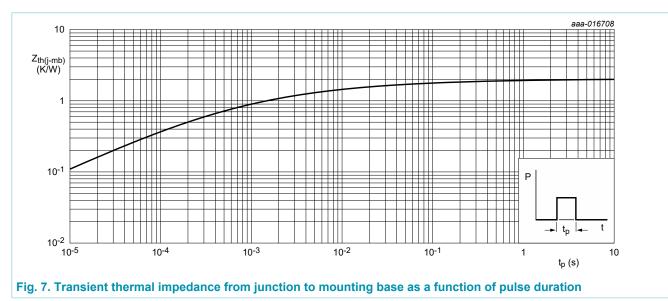
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9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance	half cycle	-	-	2.4	K/W
	from junction to mounting base	full cycle; <u>Fig. 7</u>	-	-	2	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	printed circuit board (FR4) mounted	-	55	-	K/W



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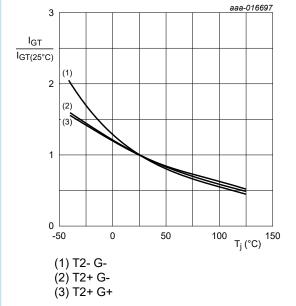
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					_
I _{GT} (gate trigger current	V _D = 12 V; I _T = 100 mA; LD+ G+; T _j = 25 °C; <u>Fig. 8</u>	5	-	35	mA
		V _D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 8</u>	5	-	35	mA
		V _D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 8</u>	5	-	35	mA
L	latching current	V _D = 12 V; I _G = 100 mA; LD+ G+; T _j = 25 °C; <u>Fig. 9</u>	-	-	50	mA
		V _D = 12 V; I _G = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 9</u>	-	-	75	mA
		V _D = 12 V; I _G = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 9</u>	-	-	50	mA
Ч	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 10</u>	-	-	40	mA
V _T	on-state voltage	I _T = 8 A; T _j = 25 °C; <u>Fig. 11</u>	-	-	1.65	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 100 mA; T _j = 25 °C; <u>Fig. 12</u>	-	0.8	1	V
		V _D = 400 V; I _T = 100 mA; T _j = 125 °C; <u>Fig. 12</u>	0.2	0.45	-	V
I _D	off-state current	V _D = 800 V; T _j = 25 °C	-	-	10	μA
		V _D = 800 V; T _j = 125 °C	-	-	0.5	mA
V _{CL}	clamping voltage	I_{CL} = 0.1 mA; t_p = 1 ms; T_j = 25 °C	800	-	-	V
Dynamic ch	naracteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	1500	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	V_D = 400 V; T _j = 125 °C; I _{T(RMS)} = 6 A; dV _{com} /dt = 20 V/µs; (snubberless condition); gate open circuit	12	-	-	A/ms
		V_D = 400 V; T _j = 125 °C; I _{T(RMS)} = 6 A; dV _{com} /dt = 10 V/µs; gate open circuit	15	-	-	A/ms
		$V_D = 400 \text{ V}; \text{ T}_j = 125 \text{ °C}; \text{ I}_{T(RMS)} = 6 \text{ A};$ $dV_{com}/dt = 1 \text{ V}/\mu\text{s}; \text{ gate open circuit}$	20	-	-	A/ms

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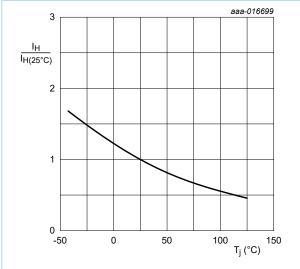
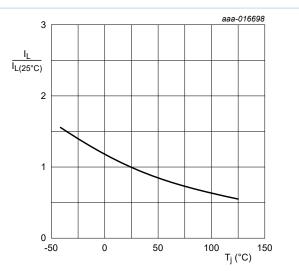
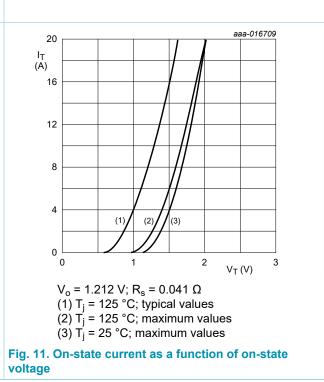


Fig. 10. Normalized holding current as a function of junction temperature



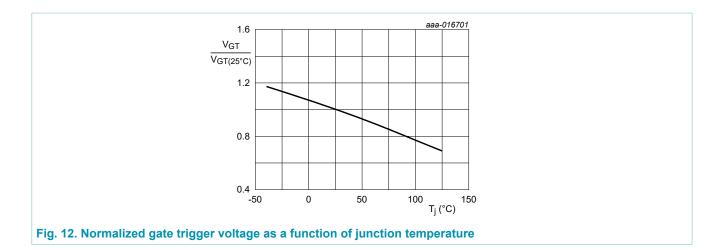




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11. Package outline

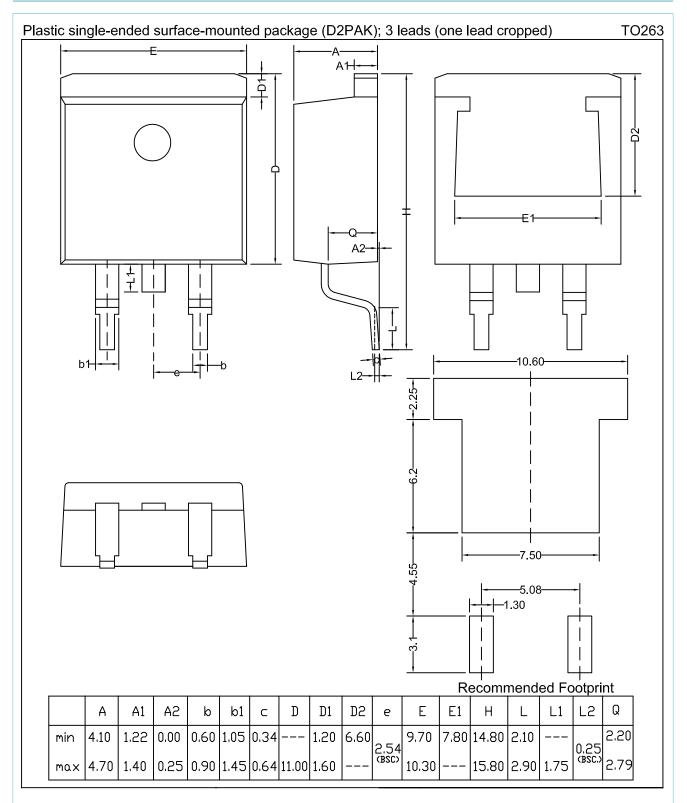


Fig. 13. Package outline D2PAK (SOT404)

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Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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[1] Please consult the most recently issued document before initiating or completing a design.

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